Review

Latest Updates of Single-Junction Organic Solar Cells up to 20% Efficiency

Boudia Mohamed El Amine 1, Yi Zhou 2, Hongying Li 3, Qiuwang Wang 1, Jun Xi 4 and Cunlu Zhao 1,∗

1 MOE Key Laboratory of Thermo-Fluid Science and Engineering, School of Energy and Power Engineering, Xi’an Jiaotong University, Xi’an 710049, China; amineboudia@stu.xjtu.edu.cn (B.M.E.A.)
2 College of General Aviation and Flight, Nanjing University of Aeronautics and Astronautics, Nanjing 210016, China
3 A*STAR Institute of High-Performance Computing, 1 Fusionopolis Way, Singapore 138632, Singapore
4 MOE Key Laboratory for Physical Electronics and Devices & Shaanxi Key Lab of Information Photonic Technique, School of Electronic Science and Engineering, Xi’an Jiaotong University, Xi’an 710049, China; jun.xi@xjtu.edu.cn
∗ Correspondence: mclzhao@xjtu.edu.cn

Abstract: Single-junction organic solar cells have reached a power conversion efficiency of 20% with narrow bandgap non-fullerene electron acceptor materials such as Y6, as well as with large bandgap electron donor materials and their derivatives. The power conversion efficiency improvement of single-junction organic solar cells is a result of highly efficient light harvesting in the near-infrared light range and reduced energy losses with the most promising active layer layout currently available, Bulk-Heterojunction. Ternary blending is known to be the most advanced strategy to construct Bulk-Heterojunction structures in organic solar cells at present. In this review, we examine different devices based on Bulk-Heterojunction structures with efficient electron donors and acceptors. Then, we review the performance of binary and ternary organic solar cells with high power conversion efficiency, in conjunction with different anode and cathode interfaces used in recent studies of high-power conversion efficiency. Finally, we present perspectives on the future development of single-junction organic solar cells.

Keywords: organic solar cells; power conversion efficiency; bulk-heterojunction; ternary configuration

1. Introduction

Organic solar cells (OSCs) have emerged as a sustainable alternative to inorganic solar cell technology for power generation [1–7]. They can be fabricated using low-temperature solution processing and are widely considered to be an efficient type of solar energy harvesting device due to their low cost, short energy payback time, and mechanical flexibility [8–11]. Recently, single-junction OSCs (which use a single layer as an active layer) utilizing wide-band-gap polymer donors (PDs) and narrow-band-gap small-molecule acceptors (SMAs) as their bulk heterojunction (BHJ) photoactive layers have led to a power conversion efficiency (PCE) exceeding 18% [12]. In most organic materials, the short exciton diffusion length, which is typically only a few nanometers, is a critically limiting factor for achieving high efficiency OSCs. BHJ exhibiting nanoscale phase separation between the donor-acceptor (D-A) mixture has been recognized for its ability to overcome the limitation of short exciton diffusion lengths [13]. Another factor that affects the PCE and stability of OSCs is the morphology of the solution-processed active layer, which is difficult to control [13–17]. The PCE, together with the devices’ durability and lifespan, are the most significant problems attributed to OSCs that hinder large-scale applications. Recent advances in OSCs include the following: the use of new
Recent investigations of single-junction OSCs with high efficiency are summarized in Table 1. In 2019, Yao et al. [20] synthesized a non-fullerene acceptor (NFA) called BTP-4Cl-12 to fabricate spin-coated OSCs within a small area (~0.09 cm²). They adopted a device structure of ITO/PEDOT: PSS/PM6: BTP-4Cl-12/PDINO/Al (ITO: indium tin oxide; PEDOT: PSS: poly (3,4-ethylene dioxythiophene): poly-(styrene sulfonate); PDINO: (perylene diimide functionalized with amino N-oxide), leading to a high PCE of 17% (16.6% as the certified value). In 2020, an active layer consisting of a mixture of the mid-band gap donor PM6 and the low-band-gap NFA Y6 showed an exceptional PCE of ~16%, a short-circuit current density (Jsc) of ~25 mA cm⁻² and a low energy loss (E_loss) of 0.5–0.6 eV [21]. Zhang et al. [22] achieved a high PCE of 17.23% using the structure of an ITO/PEDOT: PSS/PM6:Y6/PDINN/electrode. Their study used a highly conductive cathode interface of PDINN instead of PDINO. This modification dramatically impacts the electron transport and exciton diffusion at the cathode interface and also results in better contact between the non-fullerene electron acceptor and the metal electrode. In 2021, single-junction OSC cells attained a PCE of 19.0% (certified value: 18.7%) via an active layer material design with a ternary mixing technique. Namely, the mixture of a wide-bandgap polymer donor called PBQx-TF, and a low-bandgap NFA eC9-2Cl. A second NFA named F-BTA3 serves as a third component on the active layer [23]. Finally, Ram and Singh [24] studied the ternary organic solar cell (TOSC) with the structure of moth-eye-AR/glass/ITO/WS2/PBDB-T-2F: Y6: SF(BR)4/PFN-Br/Al and showed that the TOSC achieved a theoretical PCE of 20.87%, which is the highest among OSCs at present. Such a high PCE can be attributed to the tungsten disulfide (WS2) hole transport layer (HTL), which minimized the contact resistance between the active layer and the anode, leading to a high internal quantum efficiency of 91.7%. The ternary structure in OSCs can improve the stability of the device and the charge transport between the active layers. The addition of a third component to the active layer has improved the efficiency of charge extraction by the electrodes and reduced internal resistance. These highly encouraging results show great promise for large-scale production and commercialization of OSCs in the next few years.

In this review, we examine different BHJ-based OSC devices with efficient electron donors and acceptors, comparing the performance of binary and ternary OSCs. Next, we discuss different anode and cathode interfaces used in recent OSCs with high PCE. Finally, we propose solutions to problems that hinder the commercialization of OSC technology using results obtained from this study that demonstrate better-designed device structures with binary and ternary BHJ.

<table>
<thead>
<tr>
<th>Active Layer</th>
<th>Anode Layer</th>
<th>Cathode Layer</th>
<th>Jsc (mA cm⁻²)</th>
<th>Voc (V)</th>
<th>FF (%)</th>
<th>PCE (%)</th>
<th>Year</th>
<th>Ref.</th>
</tr>
</thead>
<tbody>
<tr>
<td>PM6:BTP-4Cl-12</td>
<td>PP</td>
<td>PDINO</td>
<td>25.60</td>
<td>0.858</td>
<td>77.60</td>
<td>17.00</td>
<td>2019</td>
<td>[20]</td>
</tr>
<tr>
<td>PM6:Y6</td>
<td>PP</td>
<td>PDINO</td>
<td>25.89</td>
<td>0.847</td>
<td>78.59</td>
<td>17.23</td>
<td>2020</td>
<td>[22]</td>
</tr>
<tr>
<td>PBQ6:Y6</td>
<td>PP</td>
<td>PDINN</td>
<td>26.58</td>
<td>0.851</td>
<td>77.91</td>
<td>17.62</td>
<td>2021</td>
<td>[25]</td>
</tr>
<tr>
<td>PM6:BTP-eC9</td>
<td>PP</td>
<td>PFN-Br</td>
<td>26.20</td>
<td>0.841</td>
<td>78.30</td>
<td>17.80</td>
<td>2020</td>
<td>[26]</td>
</tr>
<tr>
<td>D18:Y6</td>
<td>PP</td>
<td>PDINN</td>
<td>27.70</td>
<td>0.859</td>
<td>76.60</td>
<td>18.22</td>
<td>2020</td>
<td>[27]</td>
</tr>
<tr>
<td>PBDB-T-2F:Y6:PC71BM</td>
<td>WS2</td>
<td>PFN-Br</td>
<td>26.00</td>
<td>0.840</td>
<td>78.00</td>
<td>17.00</td>
<td>2019</td>
<td>[28]</td>
</tr>
<tr>
<td>PM6:Y6:C8-DTC</td>
<td>PP</td>
<td>PDINO</td>
<td>26.50</td>
<td>0.873</td>
<td>75.61</td>
<td>17.52</td>
<td>2020</td>
<td>[29]</td>
</tr>
<tr>
<td>PM6:BTP-eC9:PC71BM</td>
<td>PP</td>
<td>PFN-Br</td>
<td>26.93</td>
<td>0.856</td>
<td>79.40</td>
<td>18.30</td>
<td>2020</td>
<td>[30]</td>
</tr>
<tr>
<td>PBQx-TF:eC9-2Cl:F-BTA3</td>
<td>PP</td>
<td>PNDIT-F3N-Br</td>
<td>26.7</td>
<td>0.879</td>
<td>80.90</td>
<td>19.00</td>
<td>2021</td>
<td>[23]</td>
</tr>
<tr>
<td>PBDB-T-2F:Y6:SF(BR)4</td>
<td>WS2</td>
<td>PFN-Br</td>
<td>29.31</td>
<td>0.89</td>
<td>80</td>
<td>20.87</td>
<td>2020</td>
<td>[24]</td>
</tr>
</tbody>
</table>
2. Device Architecture and Working Principles

Significant progress has been made for single-junction OSCs in recent years. Most of the research has been dedicated to developing novel materials with increased charge carrier mobility and improved light absorption properties [31]. Figure 1a presents binary OSCs schematically with single junction BHJ architecture, and Figure 1b depicts the energy level diagram corresponding to the OSC in Figure 1a. As the active layer of the polymer cell absorbs the photon of incident light by either donor or acceptor, the highest occupied molecular orbital (HOMO) of the donor and acceptor materials is stimulated to its lowest unoccupied molecular orbital (LUMO), and simultaneously electron-hole pairs called excitons form in the active layer [32–34]. The excitons diffuse across the donor and acceptor phases, and then become dissociated at the interface between the donor and acceptor. The exciton dissociation consists of two steps: First, when an exciton excited in the donor reaches the D-A interface, the electron is transferred to the acceptor’s LUMO. At the same time, when an exciton excited in the acceptor reaches the D-A interface, the hole is transferred to the donor’s HOMO, which is at a lower energy level. In the second stage, the exciton will dissociate if the energy offset is at least equivalent to the exciton’s binding energy [33]. The dissociated electron is transported through the acceptor phase via its LUMO, and across the interface between the acceptor and the cathode. The dissociated hole is transported through the donor phase via its HOMO, collected at the HTL, and simultaneously transferred to the anode. The energy offsets are considered the driving force for charge transfer between organic molecules in the OSCs. The energy offset equal to the HOMO offset of the donor and acceptor ($\Delta E = E_{D}^{HOMO} - E_{A}^{HOMO}$) is released as molecular vibrational energy [33]. If $\Delta E \geq E_{B}$ (where $E_{B}$ is the exciton binding energy), the released molecule vibrational energy may separate the excitons into free electrons and holes, which are collected at the anode/cathode and may thus contribute to the photovoltaic current [33]. Consequently, decreasing these energy offsets has an immediate effect on the open-circuit voltage ($V_{oc}$) of the solar cell and, accordingly, its PCE. When light is absorbed by the acceptor molecule, a similar charge transfer process occurs, except that the exciton dissociation is prompted by the favorable transfer of a hole from the acceptor’s HOMO to the donor’s HOMO.

Figure 1. (a) Single junction BHJ architecture with a blend of polymer donor (red) and acceptor (dark) materials as the active layer. (b) Schematic of charge (hole and electron) transport in a single junction BHJ cell (Reprint with permission from Ref. [32]. 2023, Frontiers).

The relationship between electric current density and external voltage (known as $J$-$V$ curves) characterizes the electrical performance of a photovoltaic cell. Figure 2a shows typical $J$-$V$ curves for a solar cell under darkness (dashed lines) and illumination (solid lines) [26]. The $J$-$V$ curves under darkness and illumination can be predicted from Shockley’s equations as

$$J(V) = J_{0} \left[ \exp \left( \frac{eV}{n_{aq}kT} \right) - 1 \right]$$

(under darkness)
\[ J(V) = J_0 \left[ \exp \left( \frac{eV}{n k T} \right) - 1 \right] + J_{ph} \text{ (under illumination)} \]  

(2)

where the first equation describes the \( J-V \) characteristics under darkness and the second equation describes \( J-V \) characteristics under illumination; \( J_0 \) is the reverse dark current and \( V \) is the voltage, \( e \) is the electron charge, \( n \) is the diode quality factor, \( k \) is the Boltzmann constant, \( T \) is the temperature, and \( J_{ph} \) represents the light-induced current.

Figure 2a depicts the performance characteristics of solar cells, including the short-circuit current density (\( J_{sc} \)), the open-circuit voltage (\( V_{oc} \)), and the maximum operational power (\( P_{max} \)) that determines the fill factor (\( FF \)). \( V_{oc} \) is the maximal voltage that corresponds to zero current in the solar cell, while the short-circuit current density represents the maximal current density that corresponds to zero voltage across the solar cell. \( FF \) is defined as the ratio of \( P_{max} \) to the maximum power extractable from an ideal solar cell (evaluated as a product of the device area (\( A \)), \( V_{oc} \) and \( J_{sc} \)). The PCE (\( \eta \)) is the ratio of the solar cell’s maximum operational power to the incident light’s input power. Therefore, for an incident light intensity of \( I_{in} \), \( FF \) and PCE (\( \eta \)) can be expressed as [8,25,27–30,35–41]:

\[ FF = \frac{P_{max}}{A J_{sc} V_{oc}} \]  

(3)

\[ \eta = \frac{I_{oc} V_{oc}}{I_{in}} \]  

(4)

The \( FF \) has a direct correlation with the efficiency of charge extraction in OSCs. Low \( FF \) indicates a larger loss of charge carriers due to molecular recombination at the donor-acceptor interface and the intermediary layers interfaces in BHJ OSCs [8].

![Figure 2. (a) J-V curves of a solar cell under darkness and light, as well as the corresponding photovoltaic characteristics; (b) J-V curves with the “S-kink” feature (Reprint with permission from Ref. [32], 2023, Frontiers).](image)

One key factor contributing to the improved performance of organic solar cells is the efficient transfer of charge across various interfaces within the device. The type and quality of the layers between the interfaces of a solar cell affect the charge transfer across the interfaces and, hence, the PCE and \( FF \). Due to poor interfacial conditions, many practical organic BHJ devices show the “S-kink” feature in the \( J-V \) characteristics (see Figure 2b), indicating the reduction of \( FF \) and PCE within the BHJ solar cell. In addition to interfacial properties, oxygen doping, the presence of organic contaminants, vertical phase segregation, low surface recombination, and the creation of charge dipoles all contribute to the development of the “S-kink.” When producing high-quality BHJ solar cells, it is essential to perform comprehensive characterization to have proper control over crucial physical characteristics, such as layer thickness, interfacial conditions, and morphology. The morphologies of thin film materials can change over time at room temperature during operation, and thus morphologies of materials in different layers of
the solar cell gradually become unstable as they naturally degrade. These morphological changes in the active layer are dependent on the fabrication process [26,42,43].

There are more advanced configurations of OSCs beyond the conventional configuration shown in Figure 2a, such as the ternary configuration shown in Figure 3. Figure 3a presents the film absorption spectra of the three active materials of ternary OSCs, namely, donor 1 (D1), donor 2 (D2), and acceptor (A)). Ternary solar cells made up of donor 1 (D1), donor 2 (D2), and acceptor (A) exhibit the benefits of a straightforward device design (Figure 3b) and a broad range for photon capturing. Unlike the traditional binary solar cells, the mechanism behind the photovoltaic process in ternary solar cells is not simply a combination of the photovoltaic processes of individual cells. Three key concepts play roles in ternary solar cells: charge transfer, energy transfer, and parallel-linkage or alloy structure, which are greatly impacted by the presence of the third component (either the second donor or acceptor) in the ternary active layer [35]. The third component in the ternary system can be integrated within the donor, fully incorporated in the acceptor, situated at the interface between the donor and acceptor, or create its own pathways (as shown in Figure 3b).

Figure 3. The schematic configuration of a ternary OSCs: (a) Film absorption spectra of three active materials; (b) Ternary BHJ architecture with four potential active layer morphologies based on the placement of the third component. (Reprint with permission from [35]. 2023, Royal Society of Chemistry).

2.1. Binary OSC Structure

The use of NFAs in OSCs has led to a PCE as high as 18% [26,29,30,35,36]. In 2019, Yao et al. [20] used a highly efficient NFA BTP-4Cl in the active layer of the OSCs and studied the performance of the OSC materials under different processing conditions. Impressively, the device with PBDB-TF: BTP-4Cl-12 as the active layer materials achieved a PCE of 17.0% for an active layer area of 0.09 cm². The same team published another study in 2020 with the same processing conditions and active layer structure [25]. The study shows that the single-junction OSCs with BTP-eC9 (only modifying the electron acceptor) extracted from Y6 (BTP-4F) by modification of alkyl chains has achieved a PCE of 17.8%. These results show the importance of the alkyl chain modification in light absorption and power conversion. The authors hypothesized that by further improving donor materials or device engineering with multiple-compound mixing and morphological control, a greater PCE may be attained. A comparison of the photovoltaic performance of the two studies shows that the use of NAF BTP-eC9 leads to $V_{oc} = 0.839 \, \text{V}$, $J_{sc} = 26.2 \, \text{mA cm}^{-2}$ and $FF = 0.811$ [25], and the other use of BTP-4Cl-12 produces $V_{oc} = 0.858 \, \text{V}$, $J_{sc} = 25.6 \, \text{mA cm}^{-2}$ and $FF = 0.776$ [20]. Typically, the PCE for a PBDB-TF: BTP-4Cl-12 structure is lower than that of a PBDB-TF: BTP-eC9 structure due to low $J_{sc}$ and $FF$ values. To investigate the cause of the enhancement of BTP-eC9 based OSCs, Yao et al. [20] conducted photoinduced charge carrier extraction in linearly increasing voltage (photo-CELIV) measurements to
characterize the mobility of the charge carriers in the working OSCs. The charge carrier (electrons) mobilities are determined to be $2.78 \times 10^{-4}$ and $2.92 \times 10^{-5} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ for the devices based on BTP-eC9 and BTP-4Cl-12, respectively. Then, they varied the light intensity ($P_{\text{light}}$) from 1 to 100 mW cm$^{-2}$ and analyzed the impact of the $P_{\text{light}}$ on the photovoltaic parameters ($J_{\text{sc}}$ and $V_{\text{oc}}$). The slope ($S'$) of $\Delta V_{\text{oc}}$ versus $\Delta \ln (P_{\text{light}})$, is acknowledged as a strong indicator of trap-state-assisted charge recombination. The calculated $S'$ values are 1.04 and 1.19 $kT/e$ for BTP-eC9 and BTP-4Cl-12 based devices, respectively, under the same processing conditions. The low $S'$ value of the BTP-eC9-based device implies that trap-assisted recombination is suppressed in the device. The significantly increased $S'$ value of BTP-4Cl-12 is one of the main reasons for its decreased PCE. The results show that a PBDB-TF: BTP-eC9 based device has less charge carrier recombination, which contributes to the high PCE. To understand the reasons for these results more thoroughly, they performed morphology characterization of the active layer films using atomic force microscopy (AFM). The surface roughness is 1.34 nm and 7.92 nm for PBDB-TF: BTP-eC9 and PBDB-TF: BTP-4Cl-12 devices, respectively, indicating a large difference between the two devices. The first structure has proper crystallinity, high solubility, and aggregation properties, while the second does not. High solubility and aggregation properties can significantly improve the morphology of the acceptor/donor blend, thereby enhancing the crystallinity inside the material and the PCE of the device. In 2020, Ma et al. [29] produced a binary BHJ device based on PM6: Y6 (1:1.2, w/w), giving rise to a PCE of 16.20% with a $V_{\text{oc}}$ of 0.846 V, a $J_{\text{sc}}$ of 25.6 mA cm$^{-2}$ and an FF of 73.88%. The PM6:C8-DTC (1:1.2, w/w) based binary device has a lower PCE of 12.06%, a higher $V_{\text{oc}}$ of 0.952 V, a lower $J_{\text{sc}}$ of 16.87 mA cm$^{-2}$, and a higher FF of 75.03% [29]. Materials such as PM6, PBQ6, D18, and PBDB-T-2F are some of the most commonly used electron donors that have been developed and studied in the past decade. In 2020, Liu et al. [27] disclosed a polymer donor called D18 using a fused-ring acceptor unit, i.e., dithieno[3',2',3,4';2,3']benzo[1,2-c][1,2,5] thiadiazole (DTBT), and found that the D18: Y6 BHJ structure solar cells achieved a PCE of 18.22% (certified 17.6%). Solar cells in this study have a structure of ITO/PEDOT: PSS/D18: Y6/PDINN/Ag. The active layer has a thickness of 103 nm with no additive content, and the solvent vapor annealing time is 5 min. Figure 4a represents the chemical structures of different materials of D16, D18, and Y6. To investigate the absorption of light and photovoltaic parameter output more thoroughly, the researchers measured the absorption spectra for D18 in chloroform and as film in Figure 4b. Generally, D18 shows an absorption band at 400–620 nm. The light absorption peaks at 586 nm for D18 film, corresponding to an energy gap ($E_g$) of 1.98 eV. The absorption spectra of the Y6 film are complementary to those of D18. Cyclic voltammetry (CV) measurements were used to determine D18’s HOMO and LUMO energy levels, which are $-5.51$ eV and $-2.77$ eV, respectively, while Y6 shows a HOMO of $-5.65$ eV and a LUMO of $-4.10$ eV (see in Figure 4c). The external quantum efficiency (EQE) spectrum for D18 at 460–740 nm is higher than 80%, with a maximum of 87% at 540 nm, which leads to effective photocurrent creation [27].
Another work by Zhu et al. [25] conducted in 2021 shows that a binary OSC based on PBQ6:Y6 achieved a high PCE of 17.62%. The absorption of PBQ6 peaks at 634 nm with an absorption band of 300–750 nm, which is significantly wider than that of D18. The HOMO and LUMO energy levels of PBQ6 are −5.64 eV and −3.18 eV, respectively, while Y6 shows a HOMO of −5.72 eV and a LUMO of −4.06 eV. In comparison with D18 and PBQ6, Y6 has a narrower band gap. The EQE spectra indicate that the device shows a strong photo response on the visible wavelength range of 430–830 nm, and the maximum value of EQE surpassed 85%, with an even stronger photo response in the wavelength range of 600–800 nm. Compared to the D18:Y6 structure, the PBQ6:Y6 structure has a significantly broader EQE spectrum due to large band gaps in the energy diagram. The photo-CELIV measurement indicates that the D18:Y6 structure shows a carrier extraction mobility of $1.59 \times 10^{-3}$ cm$^2$ V$^{-1}$ s$^{-1}$, and the PBQ6:Y6 structure shows a carrier extraction mobility of $1.43 \times 10^{-4}$ cm$^2$ V$^{-1}$ s$^{-1}$. The PCE of the best D18:Y6 cells was 18.22%, with a Voc of 0.859 V, a $J_{sc}$ of 27.70 mA cm$^{-2}$ and an FF of 76.6%. The PBQ6:Y6 based devices demonstrated a PCE of 17.62%, with a Voc of 0.851 V and a $J_{sc}$ of 26.58 mA cm$^{-2}$ and an excellent FF of 77.91%. The reported PCE was the highest among the OSCs, using quinoxaline-based polymers as donors. Compared to the PBQ6:Y6 based devices, the D18:Y6 based device has a lower value in FF but higher values in $J_{sc}$ and Voc due to its high carrier mobility and reduced charge recombination. Another electron donor material with high performance is PBDB-T-2F. Lin et al. [28] investigated the binary cells with the blend of PBDB-T-2F: Y6 as the active layer and showed a PCE of 15.30%, a Voc of 0.850 V, a $J_{sc}$ of 25.02 mA cm$^{-2}$ and an FF of 72.0% for the investigated cells. The Voc value is significantly approaching those of the two studies mentioned above, but the values of $J_{sc}$ and FF are significantly lower. This is due to the decreased material crystallinity and increased charge recombination in the active layer of PBDB-T-2F: Y6.

In summary, to improve the next generation of OSC technology, it is important to focus on making changes to the material structure, particularly via alkyl chain modification. Additionally, optimizing the wide band gap donors and non-fullerene acceptors, which should have high solubility and aggregation properties, can improve the
material’s morphology and crystallinity properties, leading to the creation of more excitons.

2.2. Ternary OSC Structure

Ternary blending in the active layers has proven to be a viable method for achieving high OSC efficiency [27,30,37]. In 2020, Ma et al. [29] fabricated the ternary devices with PM6 as the donor material and Y6 and C8-DTC as the acceptor materials (see their chemical structures in Figure 5a). Ternary OSCs featuring PM6: Y6: C8-DTC have a PCE of 17.52%, with a $V_{oc}$ of 0.873V, a $J_{sc}$ of 26.50 mA cm$^{-2}$ and an FF of 75.61%. In comparison with the previous work on a binary structure (PM6: Y6) with a PCE of 17.23% [22], the study by Ma et al. [29] suggests that the third component (C8-DTC) enhances the PCE. Figure 5c depicts the UV-Vis absorption band of the three photovoltaic materials employed in the ternary OSCs. Y6 shows an absorption band between 700nm and 950 nm with a peak at 840 nm; PM6 displays an absorption band of 400–700 nm with an absorption peak at 600 nm; C8-DTC demonstrates a narrow absorption band between 600 nm and 800 nm, with an absorption maximum at 730 nm. Therefore, combining these three materials results in complementary absorption across a wide wavelength range of 300 to 1000 nm. The HOMO and LUMO levels of C8-DTC were measured to be $-5.60$ eV and $-3.87$ eV, respectively. The comparison between Y6 and C8-DTC shows that C8-DTC has a higher LUMO level, as shown in Figure 5b, which is helpful for the increments of $V_{oc}$ in the ternary OSCs. The C8-DTC energy levels create an energy cascade with the HOMO and LUMO levels of PM6 and Y6; this is essential for the enhanced electron transport in ternary OSCs due to the approaching HOMO and LUMO energy levels [29]. To determine the impact of C8-DTC on the charge transport parameters of ternary OSCs, it is necessary to analyze the mobilities of charge carriers (e.g., holes and electrons). The study of the binary structure (PM6:Y6) [22] shows that the electron mobilities ($\mu_e$) and hole mobilities ($\mu_h$) of the binary blend are $3.84 \times 10^{-4}$ cm$^2$ V$^{-1}$ s$^{-1}$ and $1.66 \times 10^{-4}$ cm$^2$ V$^{-1}$ s$^{-1}$, respectively, with a $\mu_e/\mu_h$ ratio of 2.34. The study of the ternary structure (PM6: Y6: C8-DTC with a weight ratio of 1:1.08: 0.12) [29] shows that $\mu_e$ and $\mu_h$ of the ternary blend are $4.45 \times 10^{-4}$ cm$^2$ V$^{-1}$ s$^{-1}$ and $2.42 \times 10^{-4}$ cm$^2$ V$^{-1}$ s$^{-1}$, respectively, with a $\mu_e/\mu_h$ ratio of 1.8. This demonstrates that the $\mu_e$ and $\mu_h$ values of the ternary blend are greater than those of the binary blend, thereby leading to the enhancement of FF and $J_{sc}$ values of the ternary OSCs.
Figure 5. (a) Chemical structures of Y6 and C8−DTC; (b) The energy level diagrams of PM6, Y6, and C8−DTC; (c) Absorption spectra of PM6, Y6 and C8−DTC films. (Reprint with permission from [29]. 2023, Elsevier).

The superior performance of ternary cells over conventional binary cells is also partially due to the improved morphology of the active layer. The ideal binary blend films of PM6: Y6 have a surface roughness of 1.704 nm. As shown in Figure 6, the ternary blend film of PM6: Y6: C8-DTC has a lower surface roughness value of 1.246 nm. Adding C8-DTC to the PM6: Y6 system generates a nanoscale phase separation network morphology, which promotes charge carrier transfer and charge separation in the active layer.

Figure 6. AFM images of (a) binary PM6: Y6 and (b) ternary PM6: Y6: C8−DTC blend films. (Reprint with permission from [29]. 2023, Elsevier).

Lin et al. [28] presented another structure of ternary OSCs, namely, PBDB-T-2F: Y6: PC71BM. The EQE spectra for the ternary PBDB-T-2F: Y6: PC71BM cells show a high EQE beyond 600 nm. Moreover, the average internal quantum efficiency (IQE) of OSCs in the wavelength range of 350–850 nm is equal to 91.7% and presents high absorbance at the 600 nm wavelength due to the complexity of the energy levels of the three materials. The
device yields a PCE of 17% with a $V_{oc}$ of 0.84V, a $J_{sc}$ of 26.0 mA cm$^{-2}$ and an enhanced FF of 78%. Ram et al. [24] designed a similar structure but replaced Lin et al.’s [28] PC71BM with non-fullerene SF(BR)$_4$ and incorporated moth eye anti-reflecting coating on top of the glass. The modified structure of the ternary OSC in this study is moth-eye ARC/glass/ITO/WS2/PBDT-T-2F: Y6: SF (BR)$_4$/PFN-Br/Al, which yielded a PCE of 20.87%, the highest ever PCE for ternary OSCs to date. Comparison of the energy levels of two materials (SF(BR)$_4$ and PC71BM) in Figure 7 reveals that the LUMO and HOMO energy levels of SF (BR)$_4$ are $-5.78$ eV and $-3.73$ eV, respectively; the LUMO and HOMO energy levels of PC71BM are $-6.1$ and $-3.8$ eV, respectively. It is clear that the energy levels of SF(BR)$_4$ are much closer to the LUMO and HOMO levels of PBDB-T-2F and Y6 than those of PC71BM. This means that SF(BR)$_4$ shows a higher absorbance rate and better complementarity with the other two materials than PC71BM.

Figure 7. (a) Energy level diagram (energies are in eV) for BHJ based ternary OSCs with the cell structure of moth–eye AR/glass/ITO/WS2/PBDT−T−2F:Y6:SF(BR)$_4$/PFN−Br/Al; (b) Energy level diagram (energies are in eV) for BHJ based ternary OSC with the cell structure of glass/ITO/WS2/PBDT−T−2F:Y6:PC71BM/PFN−Br/Al. (Reprint with permission from [24]. 2022, Wiley).

In summary, ternary solar cells have greatly interested the organic photovoltaics community. The relevance of the third component in ternary OSCs is that it creates a broad and complementary light absorption band in the active layer and also forms an energy cascade between the energy levels (LUMO and HOMO) of the materials in the active layer, thereby facilitating the charge transport and leading to the enhancement of FF, $V_{oc}$, and PCE. By selecting the photoactive layer’s three components with care, all photovoltaic characteristics can be simultaneously improved in ternary solar cells. Furthermore, the material surface in the ternary solar cells has reduced roughness, which can result in higher solubility and aggregation properties for enhancing cell performance.

2.3. Interface Engineering

In OSCs, interfacial materials also play essential roles alongside the active layer to enhance the PCE of the device. In 2019, Lin et al. [28] reported OSCs with the ternary BHJ (PBDT−2F: Y6:PC71BM) and the HTL (PEDOT: PSS) and obtained a PCE of 16.4%, an FF of 78%, a $V_{oc}$ of 0.84 V, and a $J_{sc}$ of 26 mA cm$^2$. Under the same conditions, replacing PEDOT: PSS with WS2 as the HTL results in an augmentation of PCE to 17%, which is due to the highly conductive WS2. Measurement of the serial resistances ($R_s$) of the two devices indicates that the PEDOT: PSS based device shows higher $R_s$ than the WS2 based device, which is due to the efficient charge transport and low resistance in the WS2 HTL [28]. In 2020, Zhang et al. [21] used an aliphatic amine group functionalized PDI derivative (PDINN) and stable metals (silver and copper) in the air as the cathode interlayer material (CIM) and the top cathode of an OSC, respectively. PDINN is relatively cheap and can be easily synthesized in a laboratory. The existence of the aliphatic amine group ensures an
excellent connection between the top cathode and the active layer. The PDINN contacts NFA-based active layers tightly and shows superior electric conduction ($5.0 \times 10^{-4} \text{ S cm}^{-1}$) and charge collection abilities. Furthermore, OSCs based on PDINN show weak dependence on the change of PDINN thickness during device manufacturing, since the device PCE remains above 15.0% as the thickness of PDINN expands to 27 nm. If the same active layer (PM6: Y6) was utilized in the preparation of OSCs, the PDINO/Ag based device achieves a PCE of 15.17%, a $V_{oc}$ of 0.821 V, a $J_{sc}$ of 25.58 mA cm$^{-2}$ and an FF of 72.24%, while the PDINN/Ag based device achieves a higher PCE of 17.23%. The remarkable efficiency enhancement for PDINN/Ag-based devices can be attributed to the increment of $V_{oc}$ from 0.821 to 0.847 V, and FF from 72.24% to 78.59% [38]. These results suggest that regulating interfacial contacts with proper intermolecular modifications could enhance the performance of OSC devices.

3. Conclusions

This mini-review gives an overview of the most recent developments in single-junction OSCs with high PCE. It shows that OSCs with PCEs above 20% have been made by combining different strategies, such as new non-fullerene electron acceptors with high absorption in the solar spectrum, minimal loss in the driving force during charge separation, film shape, interfacial layer, and device engineering. The most advanced result of PCE has achieved a high value of 20.87% in ternary OSCs, which feature the addition of a third component in the active layer in comparison with the binary OSCs. The third component contributes to improvements in the energy level cascade and charge transport between the device's layers, which jointly result in a PCE higher than the binary OSCs. As seen in the reviewed studies, the binary and ternary BHJ OSCs have a significant advantage over inorganic solar cells in terms of their flexibility, low fabrication cost, less pollution, and a short energy pack-back time. However, due to the intense research efforts being devoted to OSCs, there is an opportunity to overcome these challenges and improve their PCE and stability.

For better development of the next-generation OSC technology, future investigations may focus more on modifying the structures of active materials with alkyl chains, synthesizing new donors and acceptors with high solubility and aggregation properties to create more excitons, and optimizing the ternary structure to overcome the problems that undermine the efficiency of binary OSCs.

Author Contributions: Conceptualization, B.M.E.A.; methodology, B.M.E.A.; formal analysis, B.M.E.A., Y.Z. and H.L.; investigation, B.M.E.A., Y.Z. and H.L.; resources, Q.W., J.X. and C.Z.; data curation, B.M.E.A. and C.Z.; writing—original draft preparation, B.M.E.A.; writing—review and editing, B.M.E.A. and C.Z.; supervision, J.X. and C.Z.; project administration, B.M.E.A. and C.Z.; funding acquisition, C.Z. All authors have read and agreed to the published version of the manuscript.

Funding: This work was supported by the National Natural Science Foundation of China (No. 51976157), Xi’an Science and Technology Bureau (No. 2020KJRC0057), and the Fundamental Research Funds for the Central Universities (No. xzy012020075).

Data Availability Statement: Not applicable.

Conflicts of Interest: The authors declare no conflict of interest.

References


**Disclaimer/Publisher’s Note:** The statements, opinions and data contained in all publications are solely those of the individual author(s) and contributor(s) and not of MDPI and/or the editor(s). MDPI and/or the editor(s) disclaim responsibility for any injury to people or property resulting from any ideas, methods, instructions or products referred to in the content.